

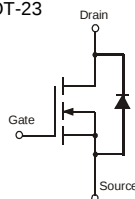
Features

- Low On-Resistance
 - 29mΩ @ $V_{GS} = 4.5V$
 - 50mΩ @ $V_{GS} = 2.5V$
 - 100mΩ @ $V_{GS} = 2.0V$
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Lead, Halogen and Antimony Free, RoHS Compliant**
- "Green" Device (Notes 2, 3 and 6)**
- Qualified to AEC-Q101 Standards for High Reliability**

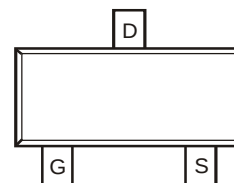


TOP VIEW

SOT-23



Equivalent Circuit



TOP VIEW

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Finish — Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)

Maximum Ratings @ $T_A = 25^\circ C$ unless otherwise specified

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V_{DSS}	20	V
Gate-Source Voltage	V_{GSS}	± 12	V
Drain Current (Note 1)	I_D	5.9	A
Pulsed Drain Current (Note 4)	I_{DM}	21	A

Thermal Characteristics

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 1)	P_D	1.4	W
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	90	$^\circ C/W$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ C$

- Notes:
- Device mounted on FR-4 PCB, on 2oz Copper pad layout with $R_{\theta JA} = 90^\circ C/W$.
 - No purposefully added lead. Halogen and Antimony Free.
 - Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 - Repetitive rating, pulse width limited by junction temperature.

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Drain-Source Breakdown Voltage	BV _{DSS}	20	—	—	V	V _{GS} = 0V, I _D = 250μA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1	μA	V _{DS} = 20V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±12V, V _{DS} = 0V
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	V _{GS(th)}	0.45	—	1.4	V	V _{DS} = V _{GS} , I _D = 250μA
Static Drain-Source On-Resistance	R _{DS(on)}	—	24	29	mΩ	V _{GS} = 4.5V, I _D = 5.0A
			42	50		V _{GS} = 2.5V, I _D = 3.1A
			68	100		V _{GS} = 2.0V, I _D = 1.5A
Forward Transfer Admittance	Y _{fs}	—	8	—	S	V _{DS} = 5V, I _D = 2.1A
Diode Forward Voltage (Note 5)	V _{SD}	—	0.9	1.4	V	V _{GS} = 0V, I _S = 2.0A
DYNAMIC CHARACTERISTICS						
Input Capacitance	C _{iss}	—	532	—	pF	V _{DS} = 10V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	144	—	pF	
Reverse Transfer Capacitance	C _{rss}	—	117	—	pF	
Gate Resistance	R _G	—	1.3	—	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz
SWITCHING CHARACTERISTICS						
Total Gate Charge	Q _g	—	6.7	—	nC	V _{DS} = 10V, V _{GS} = 4.5V, I _D = 5.0A
Gate-Source Charge	Q _{gs}	—	0.8	—		V _{DS} = 10V, V _{GS} = 4.5V, I _D = 5.0A
Gate-Drain Charge	Q _{gd}	—	3.0	—		V _{DS} = 10V, V _{GS} = 4.5V, I _D = 5.0A

Notes: 5. Short duration pulse test used to minimize self-heating effect.

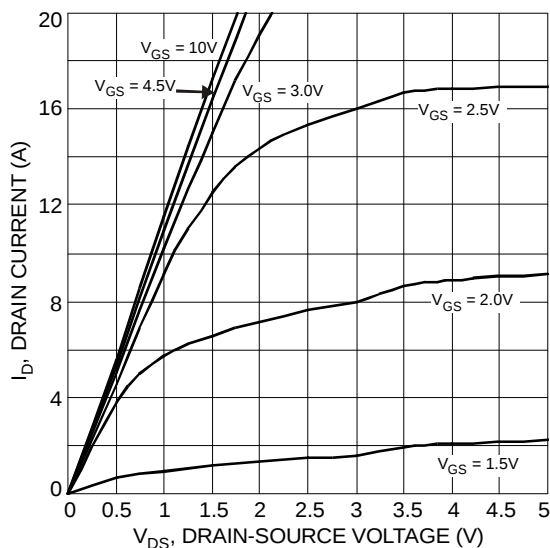
 6. Product manufactured with Green Molding Compound and does not contain Halogens or Sb₂O₃ Fire Retardants.


Fig. 1 Typical Output Characteristic

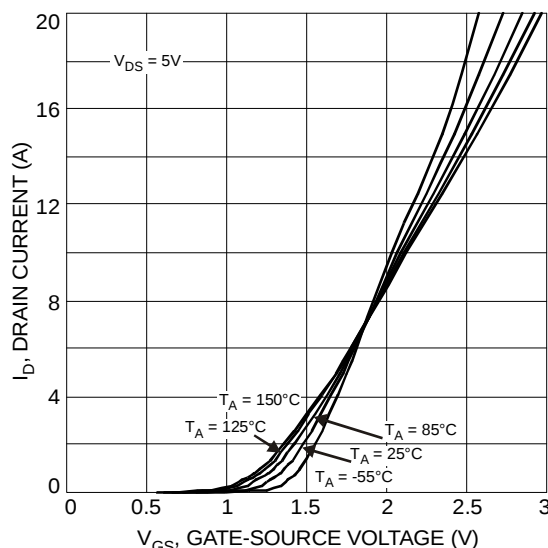


Fig. 2 Typical Transfer Characteristic

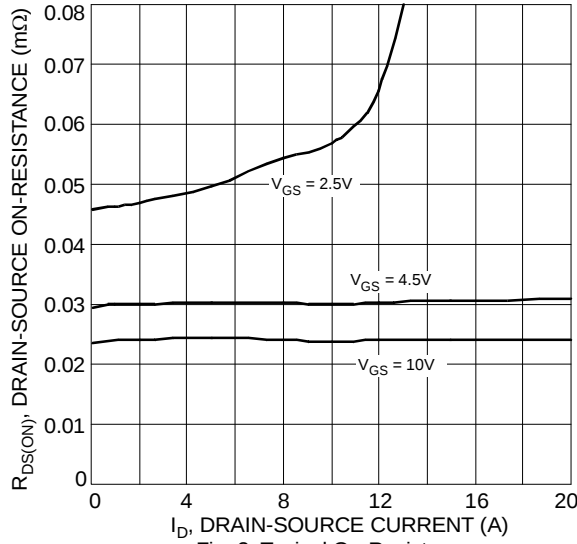


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

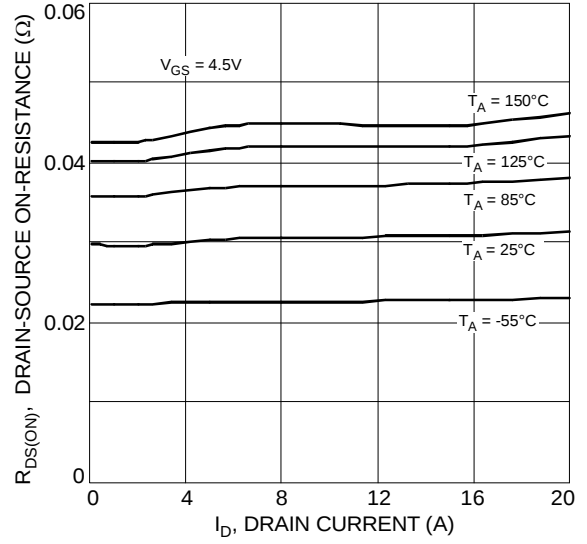


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

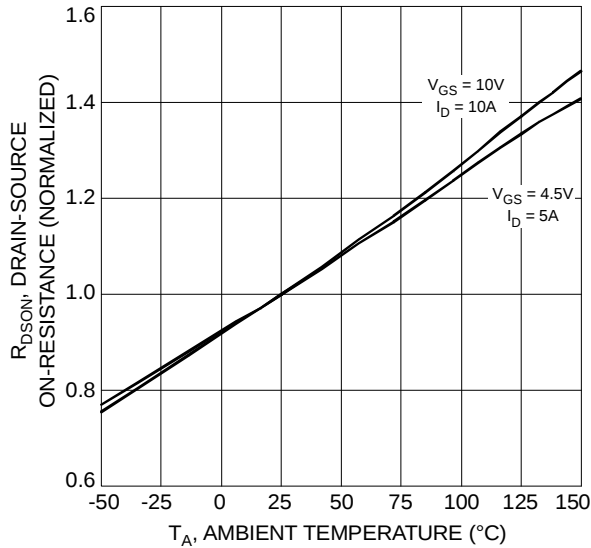


Fig. 5 On-Resistance Variation with Temperature

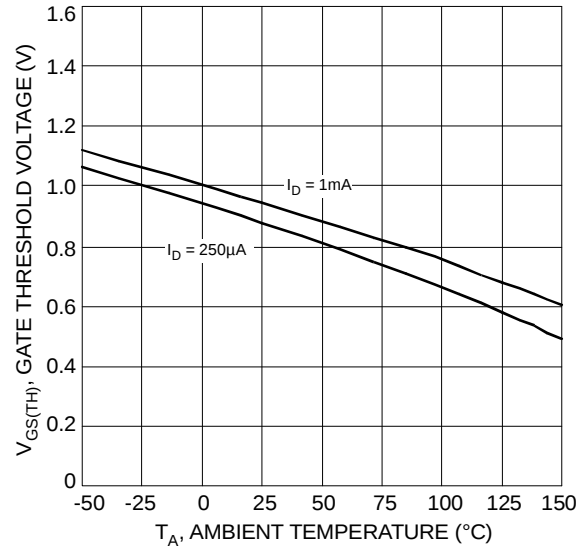


Fig. 6 Gate Threshold Variation vs. Ambient Temperature

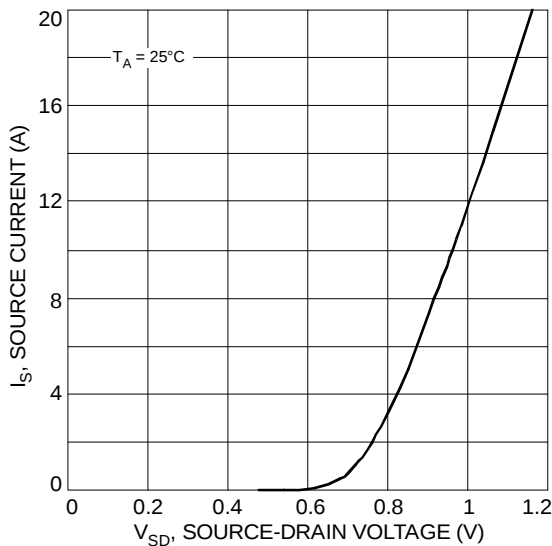


Fig. 7 Diode Forward Voltage vs. Current

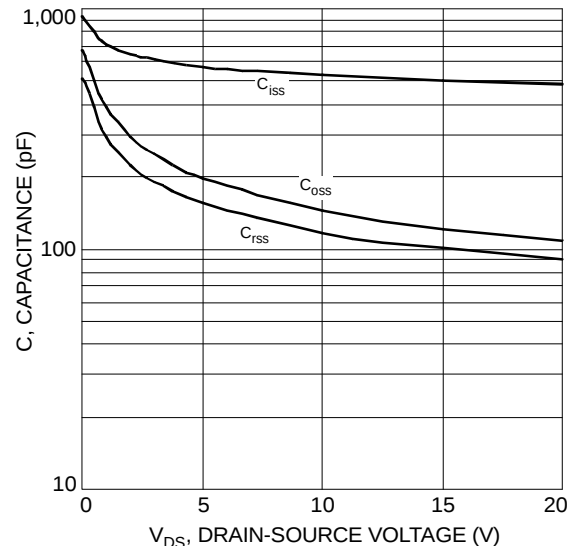


Fig. 8 Typical Total Capacitance

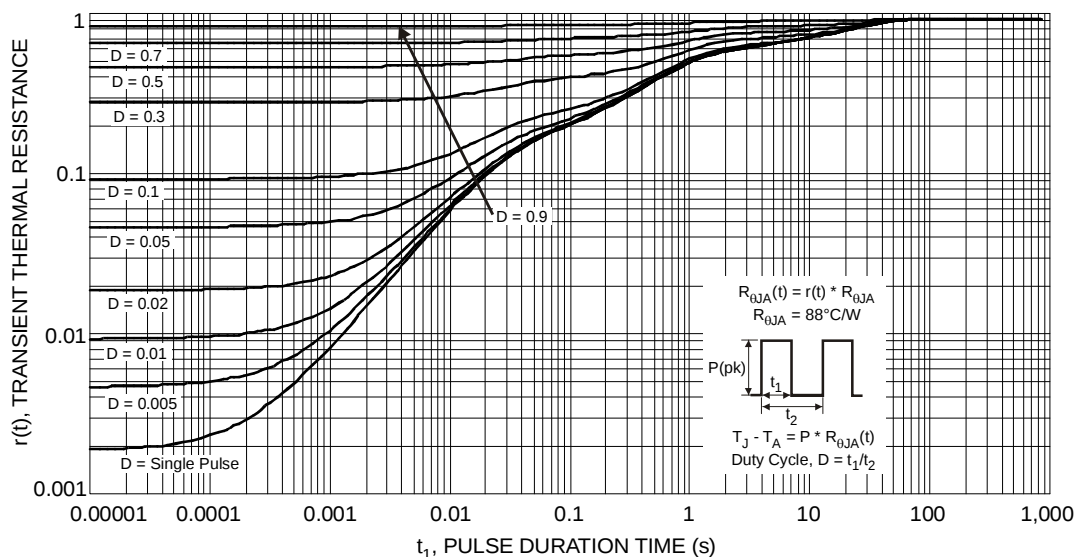


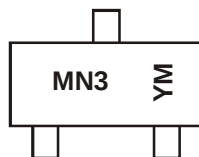
Fig. 9 Transient Thermal Response

Ordering Information (Note 7)

Part Number	Case	Packaging
DMN2050L-7	SOT-23	3000/Tape & Reel

 Notes: 7. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



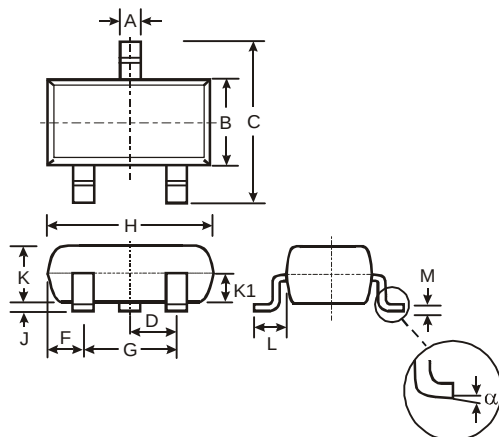
MN3 = Marking Code
 YM = Date Code Marking
 Y = Year (ex: V = 2008)
 M = Month (ex: 9 = September)

Date Code Key

Year	2008	2009	2010	2011	2012	2013	2014	2015
Code	V	W	X	Y	Z	A	B	C

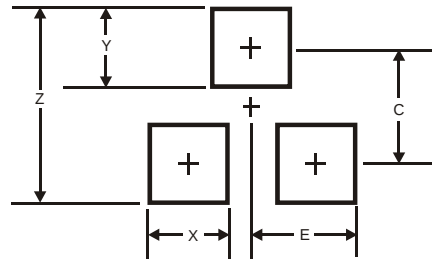
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Package Outline Dimensions



SOT-23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

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